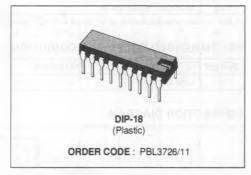
MASK - PROGRAMMABLE SPEECH CIRCUITS

SPEECH CIRCUIT

- MINIMUM NUMBER OF INEXPENSIVE EX-TERNAL COMPONENTS, 5 CAPACITORS AND 10 RESISTORS
- MUTE FUNCTION FOR PARALLEL OPERA-TION WITH DTMF GENERATOR OR DECA-DING IMPULSING
- LOW VOLTAGE OPERATION, DOWN TO 3.3V
- VERY SHORT START-UP TIME
- SIDETONE DISTORTION CANCELLATION

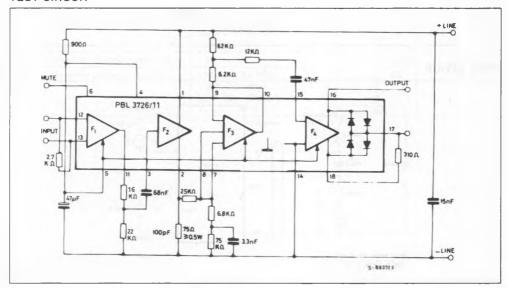
DESCRIPTON

PBL3726/11 is a standard version of the PBL3726 family of the mask-programmable, monolithic integrated speech circuits for use in electronic telephones. It is designed for use with a low impedance microphone. Sending and receiving gain is regulated with line length. Different ranges of amplifier regulation for various current feeds can be obtained with external resistor or totally cur off. Typical current feeds such as 48V $2\times200\Omega$, $2\times400\Omega$ and 36V $2\times250\Omega$ can be handled.



Application-dependent parameters such as line balance, sidetone level and frequency response are set by external components. Parameters are set independently which means easy adaptation for various market needs. An extra amplifier can be used for various purposes such as active sidetone balance.

TEST CIRCUIT



ABSOLUTE MAXIMUM RATINGS

Maximum Ratings over Operating Free-air Temperature Range (unless otherwise stated)

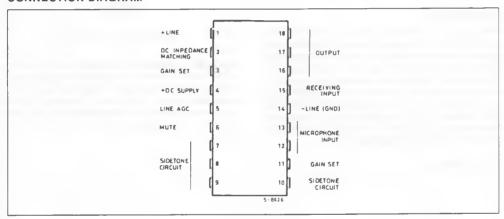
Symbol	Parameter	Test Conditions	Unit
V _{DC}	Line Voltage, t _p = 2 s	22	V
IDC (*)	Continuous Operating Line Current	100	mA
T,	Junction Temperature	150	°C
Tamb	Operating Ambient Temperature	- 40 to + 70	°C
T _{stg}	Storage Temperature	- 55 to + 150	°C

^(*) Max, current increases linearly up to 130mA with max operating temperature lowered to + 55°C.

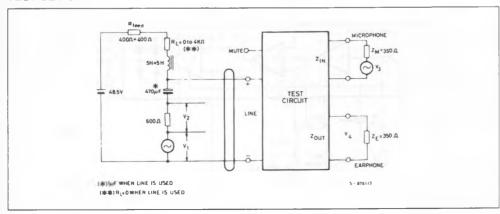
RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Тур.	Max.	Unit
IL	Line Current	15		100	mA

CONNECTION DIAGRAM



TEST SET-UP



THERMAL DATA

Rth j-amb	Thermal Resistance Junction-ambient	Max	80	°C/W

ELECTRICAL CHARACTERISTICS (electrical characteristics over recommended operating conditions)

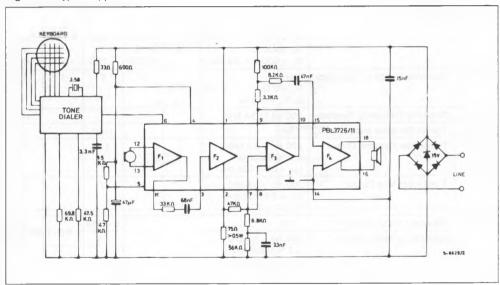
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
V _D	Terminal Voltage	I _{DC} = 15 mA I _{DC} = 100 mA	3.3 11	3.7 13	4.1 15	V
Gī	Transmitting Gain *	20 . log10 ($\frac{V_2}{V_3}$) 1 kHz R _L = 0	41 43.5 46	43 45.5 48	45 47.5 50	dB dB dB
REG⊤	Transmitting Range of Regulation	$\begin{array}{ll} 1 \text{ kHz} \\ R_L = 0 \ \Omega \\ \text{to } R_L = 900 \ \Omega \end{array} \qquad E = E + 10 \ \%$	3	5	7	dB
Lin _T	Transmitting Frequency Response	200 Hz to 3.4 kHz	- 1		1	dB
G _R	Receiving Gain *	20 . log10 ($\frac{V_4}{V_1}$) 1 kHz R _L = 0 Ω E = E + 10 % R _L = 400 Ω R _L = 900 Ω - 2.2 k Ω	- 18.5 - 16 - 13.5	- 16.5 - 14 - 11.5	- 14.5 - 12 - 9.5	dB dB dB
REGR	Receiving Range of Regulation	1 kHz $R_L = 0 \Omega$ $E = E + 10 \%$ to $R_L = 900 \Omega$	3	5	7	dB
Lin _R	Receiving Frequency Response	200 Hz to 3.4 kHz	- 1		1	dB
Z _{IN}	Transmitter Input Impedance	1 kHz		1050		Ω
V _T	Transmitter Dynamic Output	200 Hz − 3.4 kHz ≤ 2 % Distortion I _{DC} = 20 − 100 mA		1.5		Vp
V _T	Transmitter Max Output	200 Hz - 3.4 kHz I _{DC} = 0 - 100 mA V ₃ = 0 - 1 V		3		Vp
Zout	Receiver Output Impedance	1 kHz		3 + 310		Ω
	Receiver Dynamic Output **	200 Hz − 3.4 kHz ≤ 2 % Distortion I _{DC} = 20 − 100 mA V ₁ = 0 − 50 V		0.5		Vp

ELECTRICAL CHARACTERISTICS (continued)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
V _R	Receiver Max Output	Measured with Line Rectifier 200 Hz $-$ 3.4 kHz I _{DC} = 0 $-$ 100 mA V ₁ = 0 $-$ 50 V		0.9		Vp
N _T	Transmitter Output Noise	P_{sof} -weighted, REL 1 V $R_L = 0$		- 75		dB _{psof}
N _R	Receiver Output Noise	A-weighted, REL 1 V, with Cable 0-5 km Ø 0.5 mm; 0-3 km Ø 0.4 mm		- 85		dB _A
I _M	Mute Input Current		0.1			mA
IDC	Extra Available Current when Muted at the Same DC-voltage	I _{DC} = 15 - 100 mA		10		mA

Adjustable to both higher and lower values with external components.
 The Dynamic output can be doubled. See application notes at R14.

Figure 1: Typical Application.



Some typical values for R1 and R2 for some different supplies from telephone stations are shown in the next table.

Type	R1	R2
No Regulation, all Feeding Systems	00	0
48 V, 2 x 200 Ω	16 KΩ	47 ΚΩ
48 V, 2 x 400 Ω	9.1 K	47 ΚΩ